

PNP SILICON POWER TRANSISTORS

...designed for use in power amplifier applications

FEATURES:

- * Low Collector-Emitter Saturation Voltage
 $V_{CE(sat)} = 0.4 \text{ V(Max)} @ I_C = 3.0 \text{ A}, I_B = 0.15 \text{ A}$
- * DC Current Gain
 $hFE = 70-240 @ I_C = 1.0 \text{ A}$
- * High Speed Switching Time
 $t_{stg} = 1.0 \text{ us (Typ.)}$

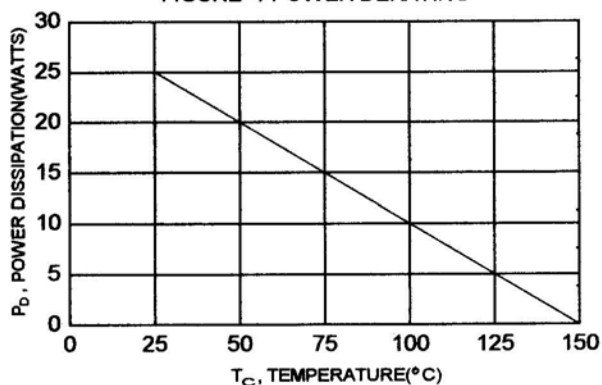
MAXIMUM RATINGS

Characteristic	Symbol	2SA1012	Unit
Collector-Emitter Voltage	V_{CEO}	50	V
Collector-Base Voltage	V_{CBO}	60	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current - Continuous	I_C	5	A
- Peak	I_{CM}	8	A
Base current	I_B	1	A
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	25 0.2	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

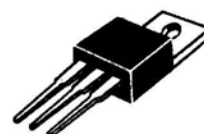
Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta jc}$	5.0	$^\circ\text{C/W}$

FIGURE -1 POWER DERATING

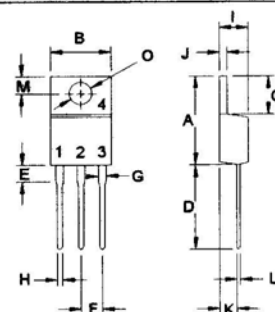


PNP
2SA1012

5 AMPERE
POWER
TRANSISTORS
50 VOLTS
25 WATTS



TO-220



PIN 1.BASE
2.COLLECTOR
3.EMITTER
4.COLLECTOR(CASE)

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	16.00
B	9.78	10.42
C	5.02	6.60
D	13.00	14.62
E	3.10	4.19
F	2.41	2.67
G	1.10	1.67
H	0.69	1.01
I	3.21	4.98
J	1.14	1.40
K	2.20	3.30
L	0.28	0.61
M	2.48	3.00
O	3.50	4.00

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ($I_C = 10\text{ mA}$, $I_E = 0$)	$V_{(BR)CEO}$	50		V
Collector Cutoff Current ($V_{CB} = 50\text{ V}$, $I_E = 0$)	I_{CBO}		10	μA
Emitter Cutoff Current ($V_{EB} = 5.0\text{ V}$, $I_C = 0$)	I_{EBO}		10	μA

ON CHARACTERISTICS (1)

DC Current Gain ($I_C = 1.0\text{ A}$, $V_{CE} = 1.0\text{ V}$)* ($I_C = 3.0\text{ A}$, $V_{CE} = 1.0\text{ V}$)	$h_{FE(2)}$ h_{FE}	70 30	240	
Collector-Emitter Saturation Voltage ($I_C = 3.0\text{ A}$, $I_B = 150\text{ mA}$)	$V_{CE(sat)}$		0.4	V
Base-Emitter Saturation Voltage ($I_C = 3.0\text{ A}$, $I_B = 150\text{ mA}$)	$V_{BE(sat)}$		1.2	V

DYNAMIC CHARACTERISTICS

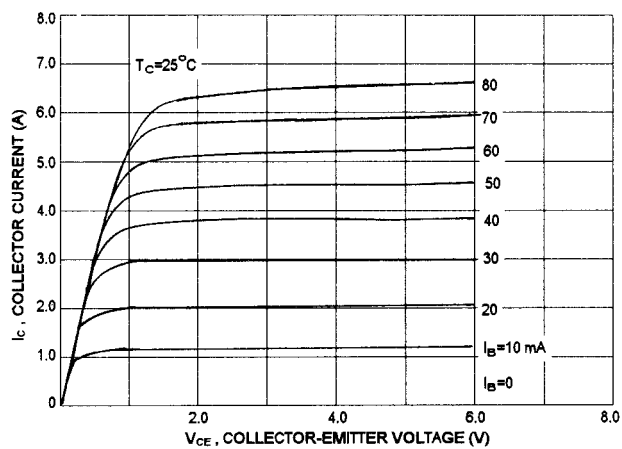
Current-Gain-Bandwidth Product ($I_C = 1.0\text{ A}$, $V_{CE} = 4.0\text{ V}$, $f = 1.0\text{ MHz}$)	f_T	10		MHz
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SWITCHING CHARACTERISTICS

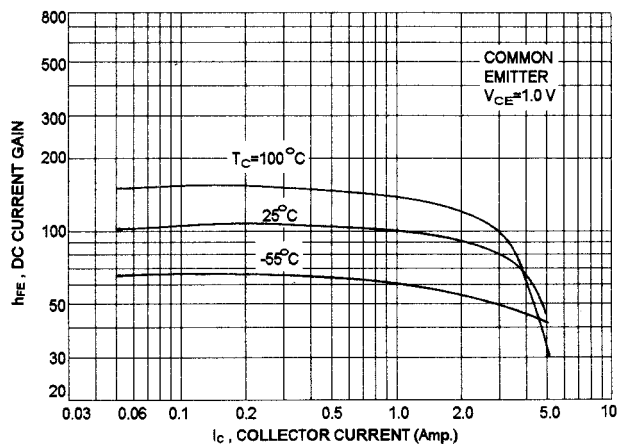
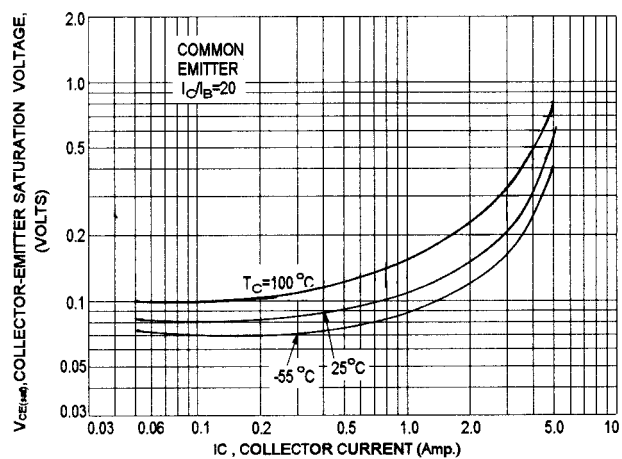
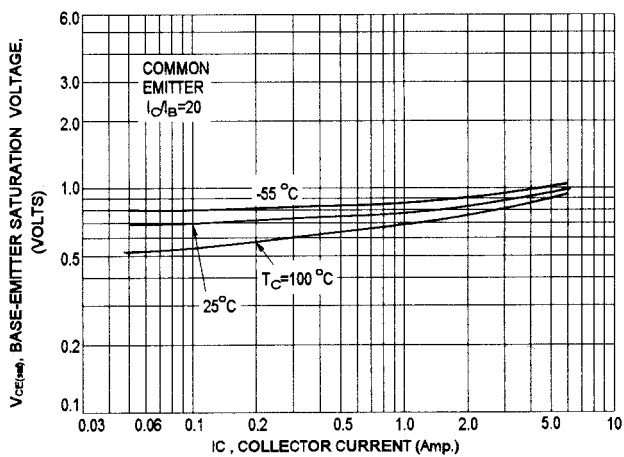
Turn-on Time	$V_{CC} = 30\text{ V}$, $I_C = 3.0\text{ A}$ $I_{B1} = -I_{B2} = 150\text{ mA}$ $PW = 20\text{ }\mu\text{s}$	t_{on}	0.2(typ)		μs
Storage Time		t_s	1.0(typ)		μs
Fall Time		t_f	0.2(typ)		μs

(1) Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$ * $h_{FE(2)}$ Classification :

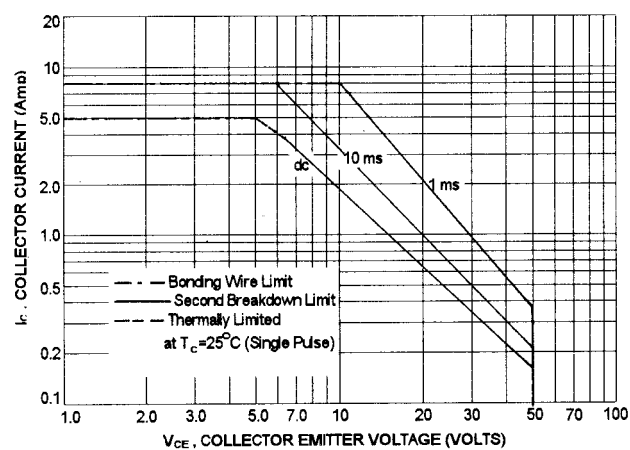
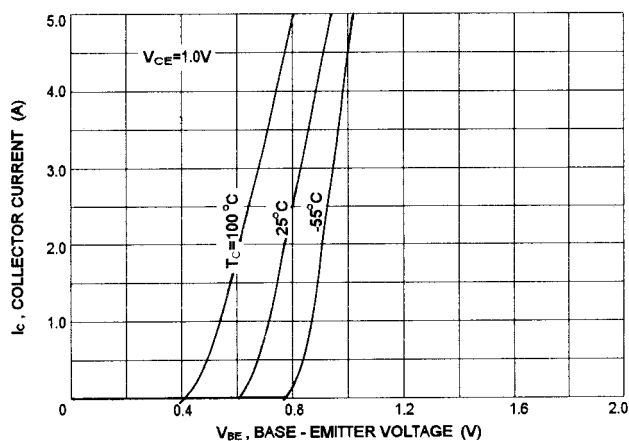
70	O	140	120	Y	240
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$I_C - V_{CE}$ 

DC CURRENT GAIN

 $V_{CE(sat)} - I_C$  $V_{BE(sat)} - I_C$ 

ACTIVE-REGION SAFE OPERATING AREA

 $I_C - V_{BE}$ 

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